HA1630S08

Single CMOS High Drive Operational Amplifier

REJ03D0908-0100
Rev.1.00
Feb 22, 2008

Description

HA1630S08 is a low power single CMOS operational amplifier featuring high output current with typical current supply of 170 μA (2.7 - 5.5 V). This IC designed to operate from a single power supply and have full swing outputs. Available in CMPAK-5 and MPAK-5 package, the miniature size of this IC not only allows compact integration in portable devices but also minimizes distance of signal sources (sensors), thus reducing external noise pick up prior to amplification. This IC exhibit excellent current drive-power ratio capable of 600 Ω load driving and yet resistant to oscillation for capacitive loads up to 400 pF.

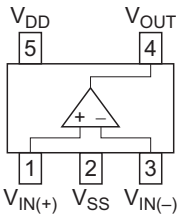
Features

- Low supply current I_{DD} = 170 μA Typ (V_{DD} = 3 V, R_L = No load)
- Low voltage operation V_{DD} = 2.7 V to 5.5 V
- Low input offset voltage V_{IO} = 6 mV Max
- Low input bias current I_{IB} = 1 pA Typ
- High output current $I_{OSOURCE}$ = 30 mA Typ (V_{DD} = 3.0 V, V_{OH} = 2.5 V)
  I_{OSINK} = 30 mA Typ (V_{DD} = 3.0 V, V_{OL} = 0.5 V)
- Input common voltage range includes ground

Ordering Information

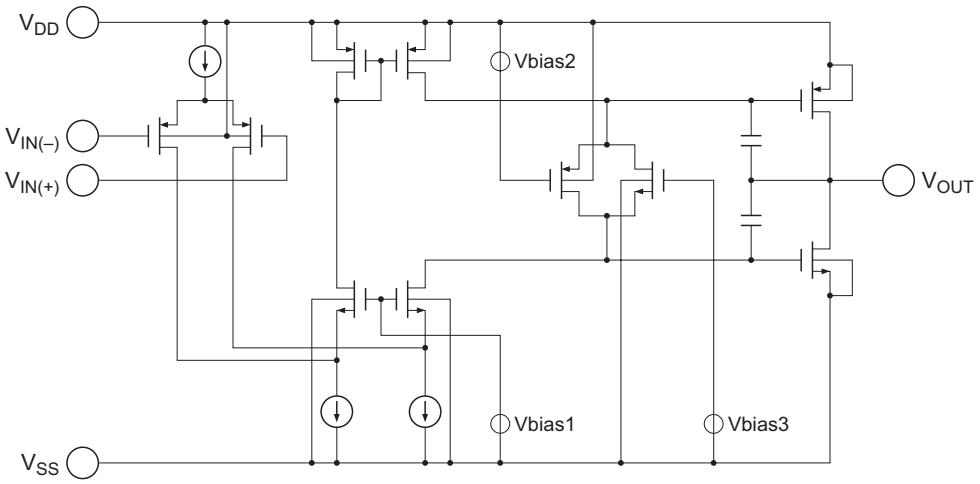
Part No.	Package Name	Package Code
HA1630S08CM	CMPAK-5	PTSP0005ZC-A
HA1630S08LP	MPAK-5	PLSP0005ZB-A

Pin Arrangement



(Top view)

Equivalent Circuit



Absolute Maximum Ratings

(Ta = 25°C)

Item	Symbol	Ratings	Unit	Note
Supply voltage	V_{DD}	7.0	V	
Differential input voltage	$V_{IN(diff)}$	$-V_{DD}$ to $+V_{DD}$	V	1
Input voltage	V_{IN}	–0.1 to $+V_{DD}$	V	
Output current	I_{OUT}	70	mA	
Power dissipation	P_T	80 (CMPAK-5)	mW	2
		120 (MPAK-5)		
Operating temperature	Topr	–40 to +85	°C	
Storage temperature	Tstg	–55 to +125	°C	

Note: 1. Do not apply input voltage exceeding V_{DD} or 7 V.
2. If Ta > 25°C,
CMPAK-5: –0.8 mW/°C
MPAK-5: –1.2 mW/°C

Electrical Characteristics

DC Characteristics

(Ta = 25°C, V_{DD} = 3.0 V, V_{SS} = 0 V)

Item	Symbol	Min	Typ	Max	Unit	Test Conditions
Input offset voltage	V_{IO}	—	—	6	mV	V_{IN} = 1.5 V, R_L = 1 MΩ
Input bias current	I_{IB}	—	(1)	—	pA	V_{IN} = 1.5 V
Input offset current	I_{IO}	—	(1)	—	pA	V_{IN} = 1.5 V
Common mode input voltage range	V_{CM}	–0.1	—	1.8	V	
Supply current	I_{DD}	—	170	500	µA	$V_{IN(+)}$ = 1.0 V, R_L = ∞
Output source current	$I_{OSOURCE}$	15	30	—	mA	Vout = 2.5 V
Output sink current	I_{OSINK}	15	30	—	mA	Vout = 0.5 V
Open loop voltage gain	A_V	55	80	—	dB	R_L = 100 kΩ
Common mode rejection ratio	CMRR	50	80	—	dB	V_{IN1} = 0 V, V_{IN2} = 1.8 V
Power supply rejection ratio	PSRR	55	80	—	dB	V_{DD1} = 2.7 V, V_{DD2} = 5.5 V
Output high voltage	V_{OH}	2.9	—	—	V	R_L = 600 Ω to V_{SS}
Output low voltage	V_{OL}	—	—	0.1	V	R_L = 600 Ω to V_{DD}

Note: ( ) : Design specification

AC Characteristics

(Ta = 25°C, V_{DD} = 3.0 V, V_{SS} = 0 V)

Item	Symbol	Min	Typ	Max	Unit	Test Conditions
Slew rate	SRr	—	(1.5)	—	V/µs	V_{IN} = 1.5 V, C_L = 15 pF
	SRf	—	(1.5)	—		(V_{INL} = 0.2 V, V_{INH} = 1.7 V)
Gain bandwidth product	GBW	—	(2.0)	—	MHz	V_{IN} = 1.5 V, C_L = 15 pF

Note: ( ) : Design specification

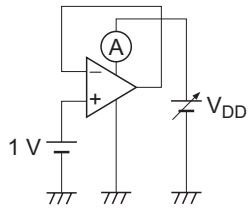
Table of Graphs

Electrical Characteristics			Characteristic Curves	Test Circuit No.
Supply current	I_{DD}	vs. Supply voltage	1	1
		vs. Temperature	2	1
Output high voltage	V_{OH}	vs. Rload	3	2
Output low voltage	V_{OL}	vs. Rload	4	3
Output source current	$I_{OSOURCE}$	vs. Output high voltage	5	4
		vs. Temperature	6	4
Output sink current	I_{OSINK}	vs. Output low voltage	7	5
		vs. Temperature	8	5
Input offset voltage	V_{IO}	vs. Supply voltage	9	6
		vs. Input voltage	10	6
		vs. Temperature	11	7
Common mode input voltage range	V_{CM}	vs. Supply voltage	12	8
		vs. Temperature	13	8
Common mode rejection ratio	CMRR	vs. Input voltage	14	9
Power supply rejection ratio	PSRR	vs. Supply voltage	15	10
Input bias current	I_{IB}	vs. Input voltage	16	11, 12
		vs. Temperature	17	11, 12
Slew rate (rising)	SRr	vs. Cload	18	13
		vs. Temperature	19	13
		Time waveform	20	13
Slew rate (falling)	SRf	vs. Cload	21	13
		vs. Temperature	22	13
		Time waveform	23	13
Open loop gain	A_V	vs. Rload	24	14
		vs. Frequency	25, 26	14
Phase margin	PM	vs. Cload	27	14
Noise input voltage	VNI	vs. Frequency	28	15

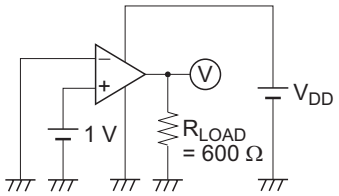
Test Circuits

(Unless otherwise noted, V_{DD} = 3 V, V_{SS} = 0 V, Ta = 25°C)

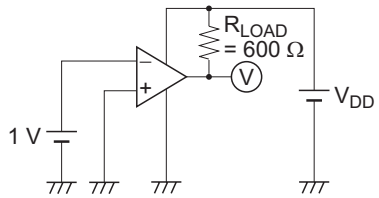
1. Supply Current, I_{DD}



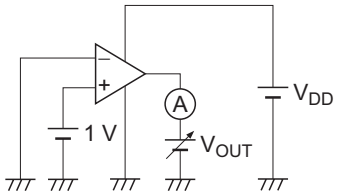
2. Output High Voltage, V_{OH} (Output High)



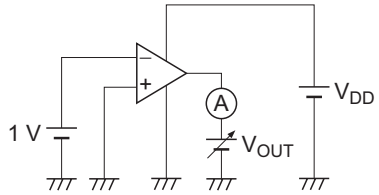
3. Output Low Voltage, V_{OL} (Output Low)



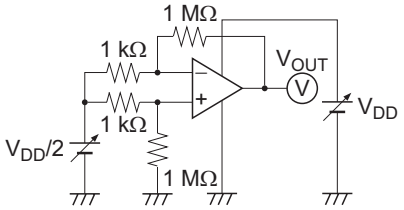
4. Output Source Current, $I_{OSOURCE}$



5. Output Sink Current, I_{OSINK}

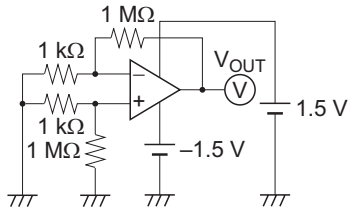


6. Input Offset Voltage vs. Operating Voltage



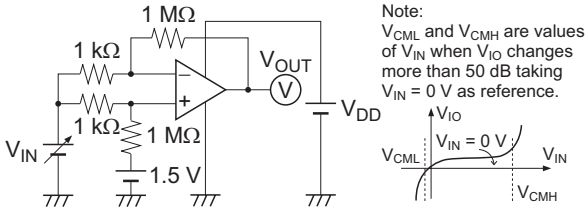
$V_{IO} = V_{OUT} / 1001$

7. Input Offset Voltage, V_{IO}



$V_{IO} = V_{OUT} / 1001$

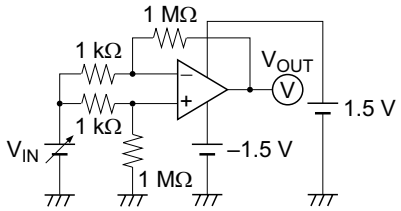
8. Common Mode Input Voltage Range, V_{CM}



Test Circuits (cont.)

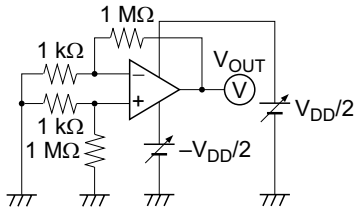
(Unless otherwise noted, V_{DD} = 3 V, V_{SS} = 0 V, Ta = 25°C)

9. Common Mode Rejection Ratio, CMRR



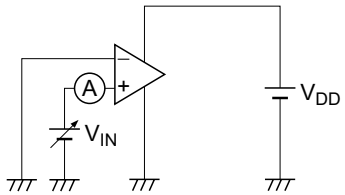
V_{IN}	Measure Point	Calculate V_{IO}	CMRR Calculation
–1.5 V	V_{OUT1}	$V_{IO1} = V_{OUT1} / 1001$	$CMRR = \left\| 20\log_{10} \frac{\|[V_{IO2} - V_{IO1}]\|}{0.3 - (-1.5\ V)} \right\|$
0.3 V	V_{OUT2}	$V_{IO2} = V_{OUT2} / 1001$	

10. Power Supply Rejection Ratio, PSRR

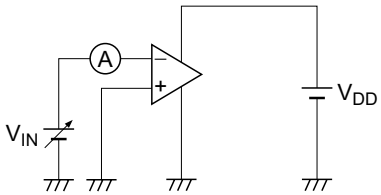


V_{DD}	Measure Point	Calculate V_{IO}	CMRR Calculation
2.7 V	V_{OUT1}	$V_{IO1} = V_{OUT1} / 1001$	$PSRR = \left\| 20\log_{10} \frac{\|[V_{IO2} - V_{IO1}]\|}{5.5\ V - 2.7\ V} \right\|$
5.5 V	V_{OUT2}	$V_{IO2} = V_{OUT2} / 1001$	

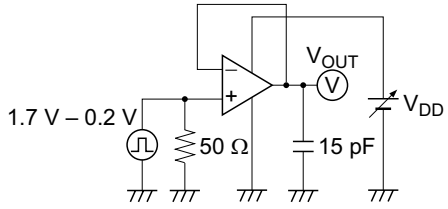
11. Input Bias Current, I_{IB+}

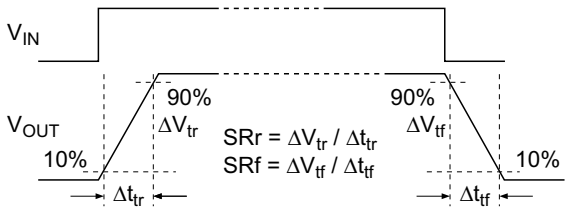


12. Input Bias Current, $I_{IB–}$



13. Slew Rate (Large Signal Input)

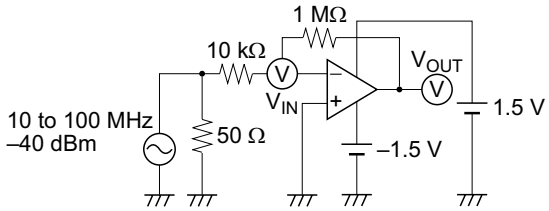




Test Circuits (cont.)

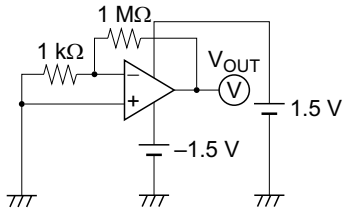
(Unless otherwise noted, V_{DD} = 3 V, V_{SS} = 0 V, Ta = 25°C)

14. Open Loop Voltage Gain, A_V



$$A_V = \left| 20\log_{10} \frac{101 \times |V_{OUT}|}{|V_{IN}|} \right|$$

15. Noise Input Voltage, VNI



$$VNI = \frac{V_{OUT}}{1001}$$

Characteristic Curves

Figure 1 HA1630S08
Supply Current vs. Supply Voltage

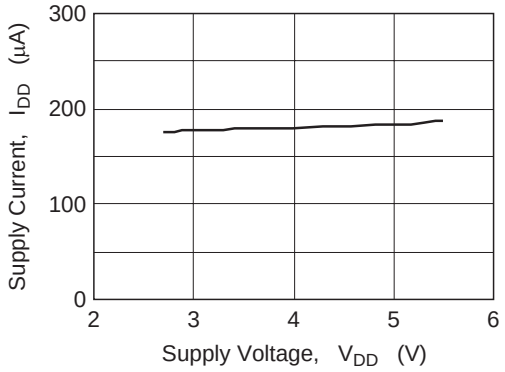


Figure 2 HA1630S08
Supply Current vs. Ambient Temperature

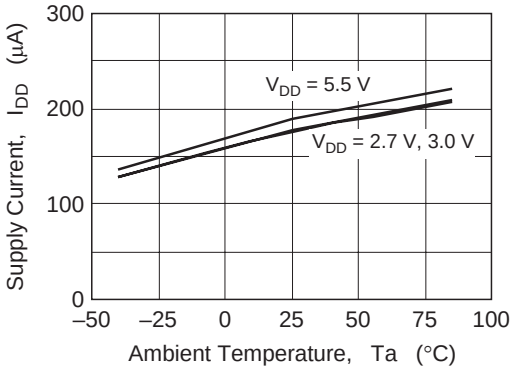


Figure 3 HA1630S08
Output High Voltage vs. Resistor Load

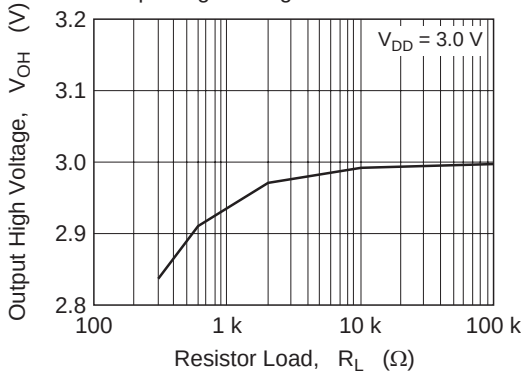


Figure 4 HA1630S08
Output Low Voltage vs. Resistor Load

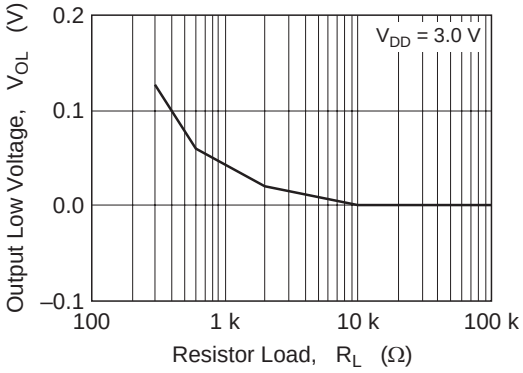


Figure 5 HA1630S08
Output High Voltage vs. Output Source Current

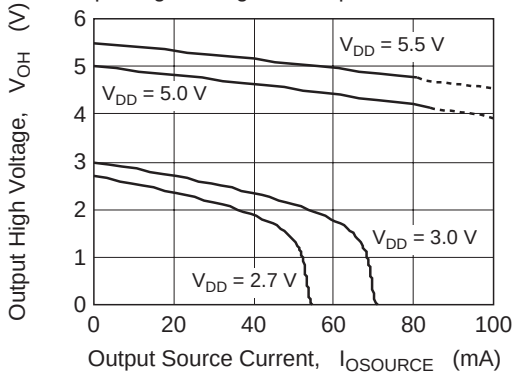
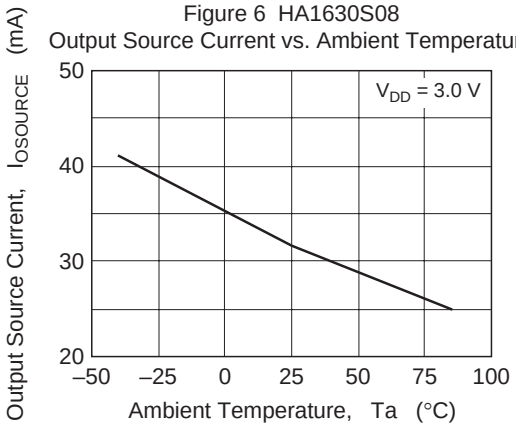


Figure 6 HA1630S08
Output Source Current vs. Ambient Temperature



Characteristic Curves (cont.)

Figure 7 HA1630S08
Output Low Voltage vs. Output Sink Current

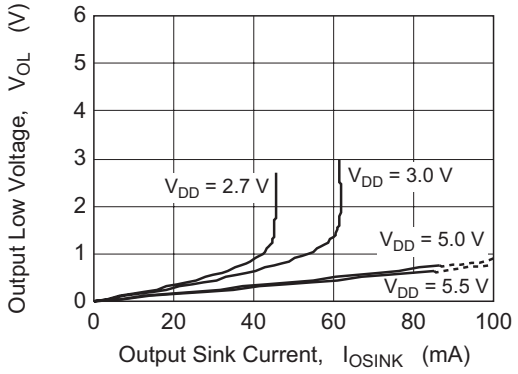


Figure 8 HA1630S08
Output Sink Current vs. Ambient Temperature

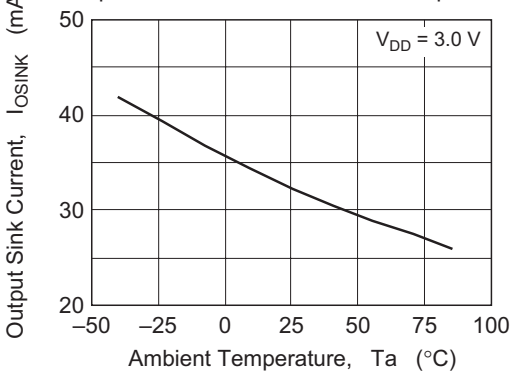


Figure 9 HA1630S08
Input Offset Voltage vs. Supply Voltage

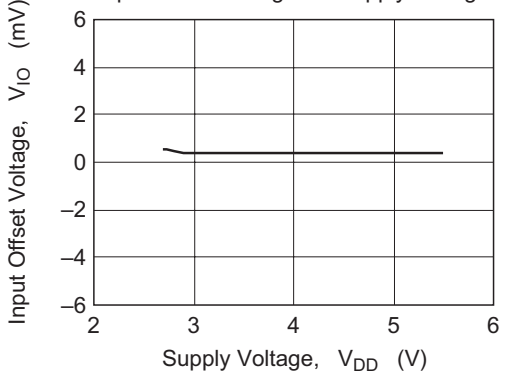


Figure 10 HA1630S08
Input Offset Voltage vs. Input Voltage

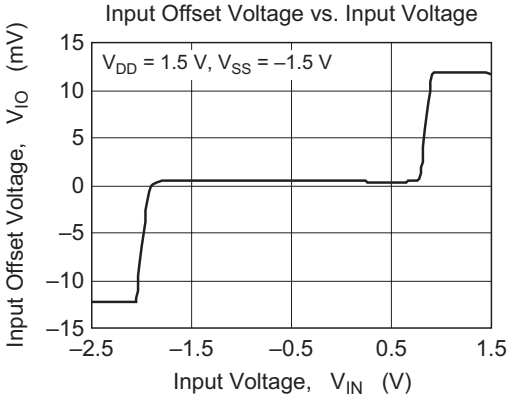


Figure 11 HA1630S08
Input Offset Voltage vs. Ambient Temperature

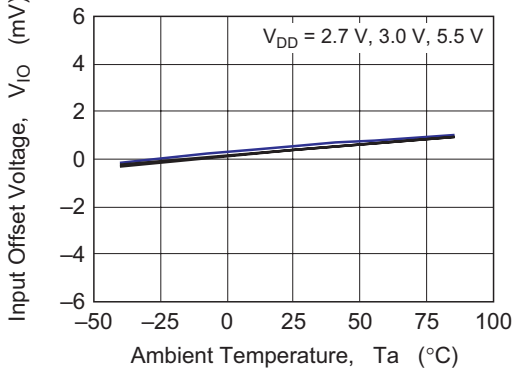
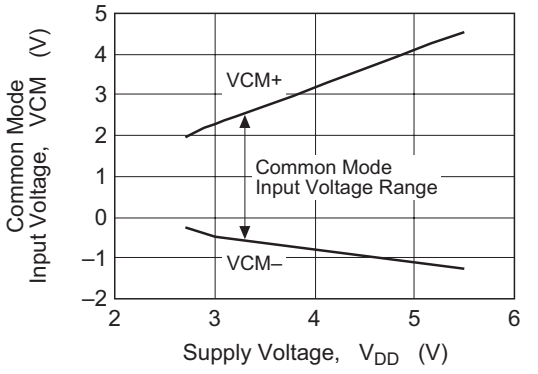


Figure 12 HA1630S08
Common Mode Input Voltage vs. Supply Voltage



Characteristic Curves (cont.)

Figure 13 HA1630S08
Common Mode Input Voltage vs. Ambient Temperature

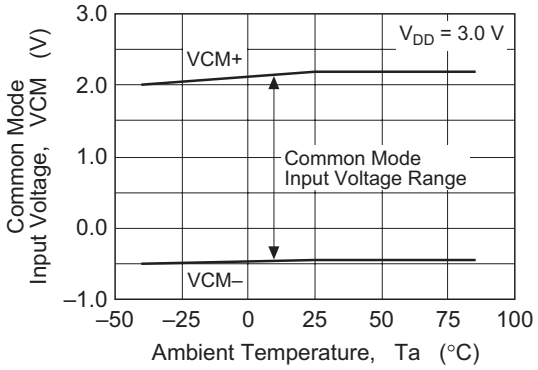


Figure 14 HA1630S08
Common Mode Rejection Ratio vs. Input Voltage

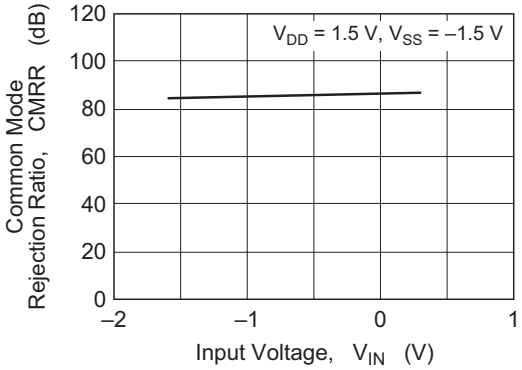


Figure 15 HA1630S08
Power Supply Rejection Ratio vs. Supply Voltage

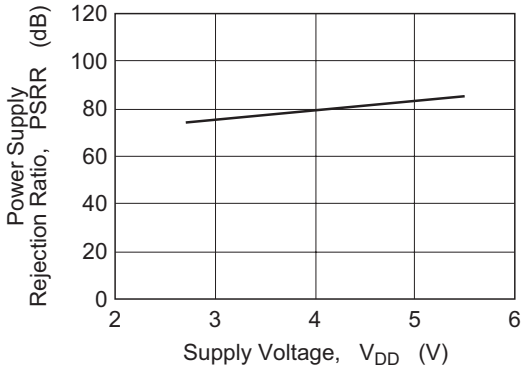


Figure 16 HA1630S08
Input Bias Current vs. Input Voltage

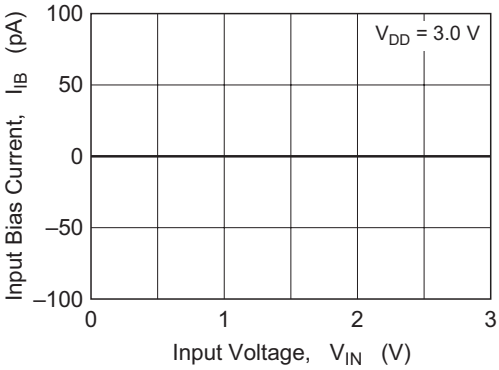


Figure 17 HA1630S08
Input Bias Current vs. Ambient Temperature

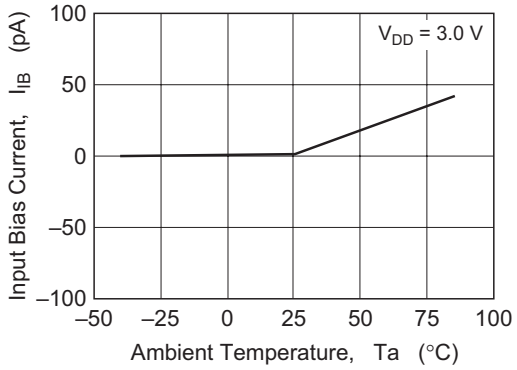
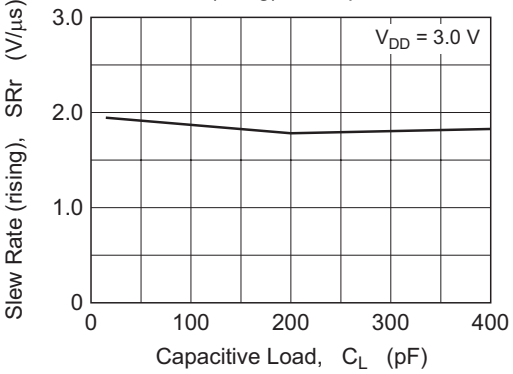


Figure 18 HA1630S08
Slew Rate (rising) vs. Capacitive Load



Characteristic Curves (cont.)

Figure 19 HA1630S08
Slew Rate (rising) vs. Ambient Temperature

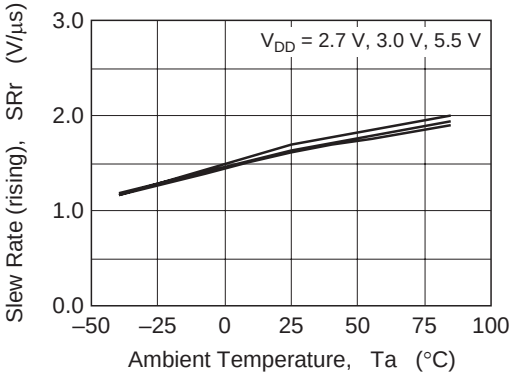


Figure 20 HA1630S08
Slew Rate (rising)

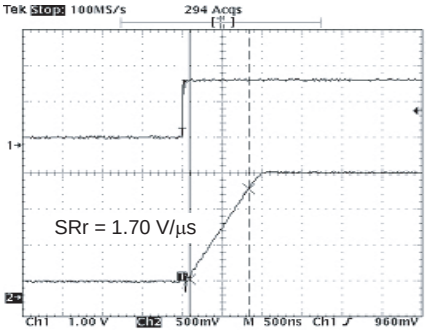


Figure 21 HA1630S08
Slew Rate (falling) vs. Capacitive Load

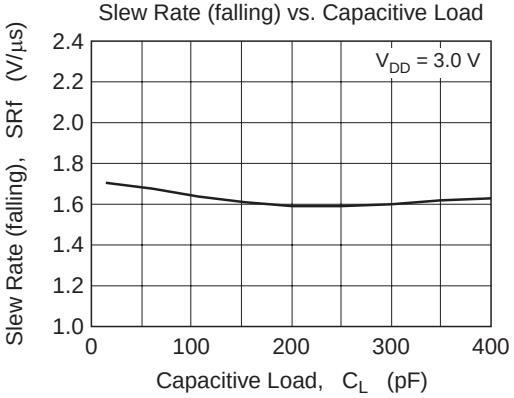


Figure 22 HA1630S08
Slew Rate (falling) vs. Ambient Temperature

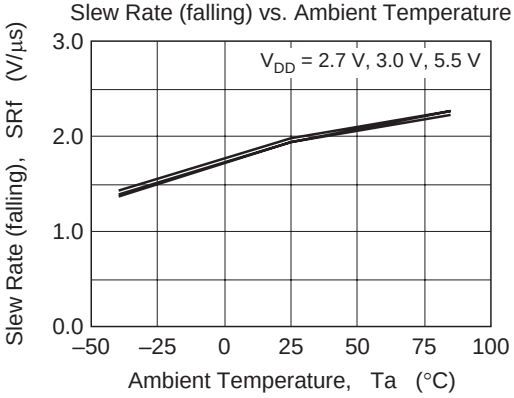


Figure 23 HA1630S08
Slew Rate (falling)

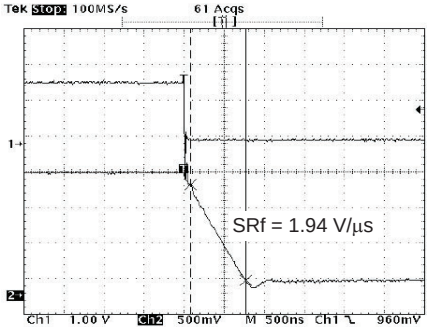
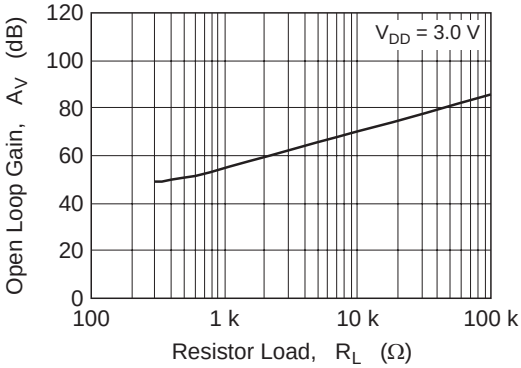


Figure 24 HA1630S08
Open Loop Gain vs. Resistor Load



Characteristic Curves (cont.)

Figure 25 HA1630S08
Open Loop Gain, Phase vs. Frequency

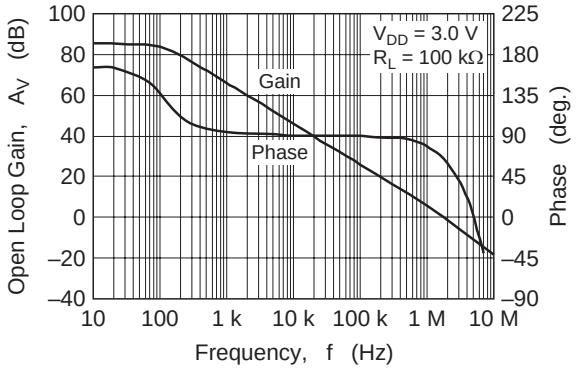


Figure 26 HA1630S08
Open Loop Gain, Phase vs. Frequency

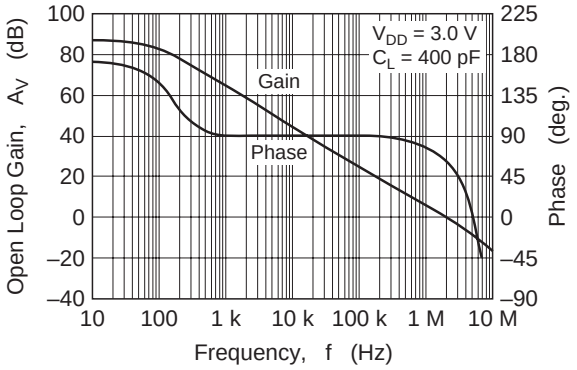


Figure 27 HA1630S08
Phase Margin vs. Capacitive Load

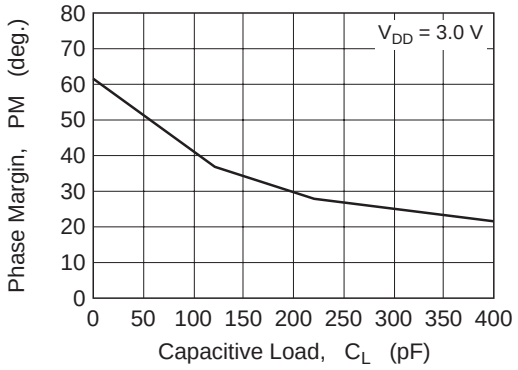
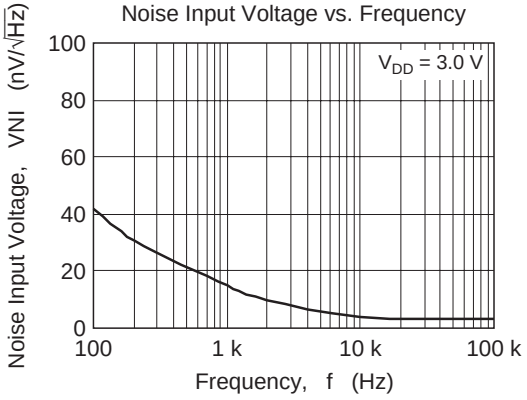
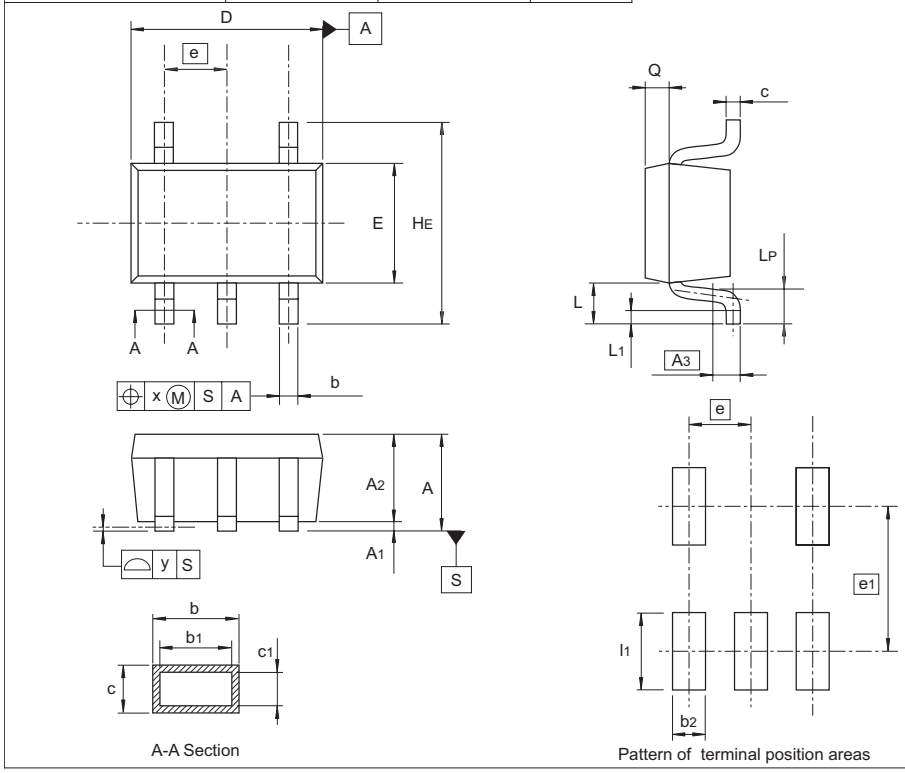


Figure 28 HA1630S08
Noise Input Voltage vs. Frequency



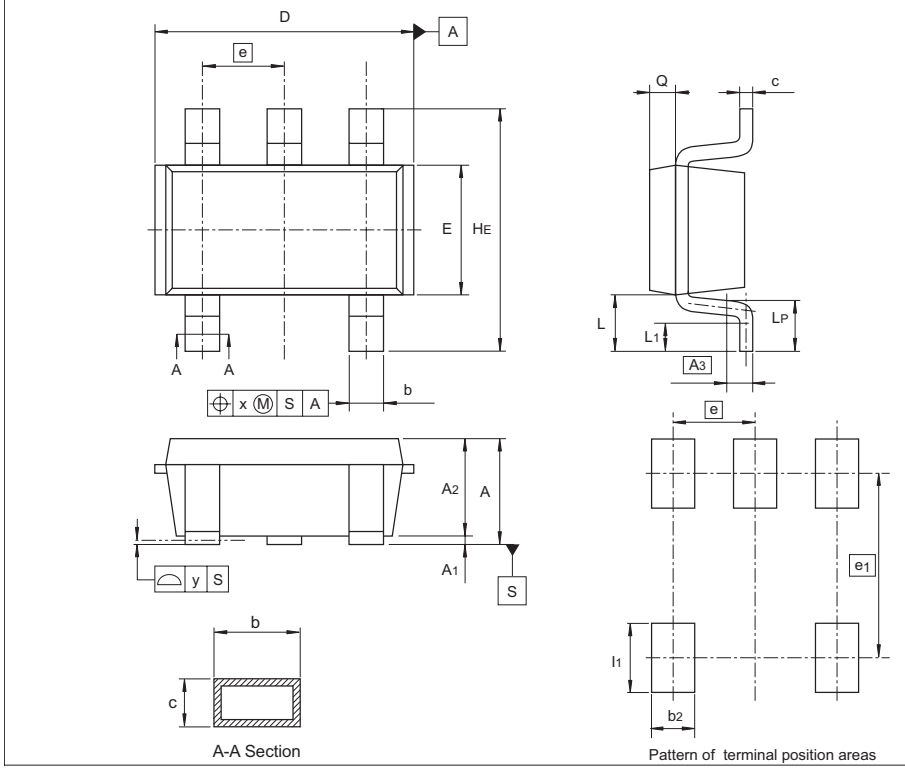
Package Dimensions

JEITA Package Code	RENESAS Code	Previous Code	MASS[Typ.]
SC-88A	PTSP0005ZC-A	CMPAK-5 / CMPAK-5V	0.006g



Reference Symbol	Dimension in Millimeters		
	Min	Nom	Max
A	0.8	–	1.1
A_1	0	–	0.1
A_2	0.8	0.9	1.0
A_3	–	0.25	–
b	0.15	0.22	0.3
b_1	–	0.2	–
c	0.1	0.13	0.15
c_1	–	0.11	–
D	1.8	2.0	2.2
E	1.15	1.25	1.35
e	–	0.65	–
H_E	1.8	2.1	2.4
L	0.3	–	0.7
L_1	0.1	–	0.5
L_P	0.2	–	0.6
x	–	–	0.05
y	–	–	0.05
b_2	–	–	0.35
e_1	–	1.5	–
l_1	–	–	0.9
Q	–	0.25	–

Package Name	JEITA Package Code	RENESAS Code	Previous Code	MASS[Typ.]
MPAK-5	SC-74A	PLSP0005ZB-A	MPAK-5 / MPAK-5V	0.015g

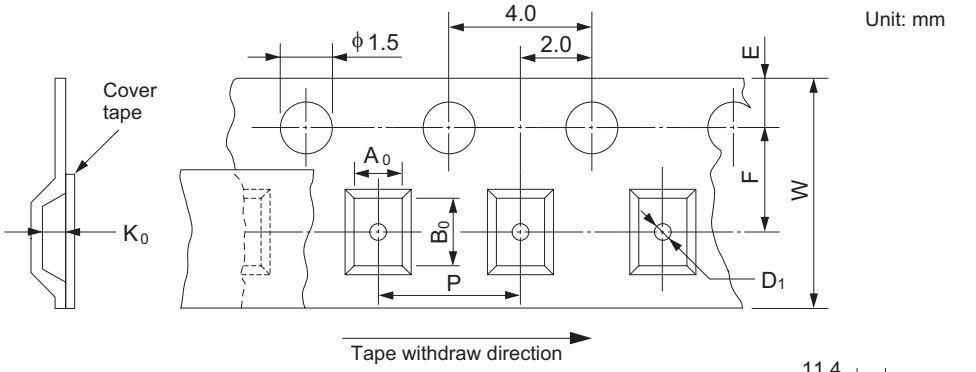


Reference Symbol	Dimension in Millimeters		
	Min	Nom	Max
A	1.0	–	1.4
A_1	0	–	0.1
A_2	1.0	1.1	1.3
A_3	–	0.25	–
b	0.35	0.4	0.5
c	0.11	0.16	0.26
D	2.8	2.95	3.1
E	1.5	1.6	1.8
e	–	0.95	–
H_E	2.5	2.8	3.0
L	0.3	–	0.7
L_1	0.1	–	0.5
L_P	0.2	–	0.6
x	–	–	0.05
y	–	–	0.05
b_2	–	–	0.55
e_1	–	2.15	–
l_1	–	–	0.85
Q	–	0.3	–

Taping & Reel Specification

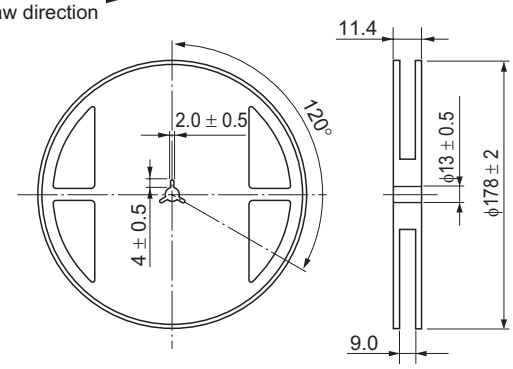
[Taping]

Package Code	W	P	Ao	Bo	Ko	E	F	D1	Maximum Storage No.
MPAK-5	8	4	3.3	3.3	1.5	1.75	3.5	1.05	3,000 pcs/reel
CMPAK-5	8	4	2.25	2.45	1.1	1.75	3.5	1.05	3,000 pcs/reel



[Reel]

Package	Tape width	W1	W2
MPAK-5	8	11.4	9
CMPAK-5	8	11.4	9

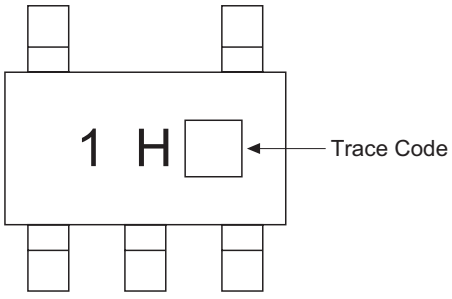


[Ordering Information]

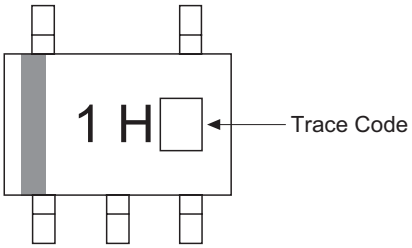
Ordering Unit
3,000 pcs

Mark Indication

• MPAK-5



• CMPAK-5



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Colophon .7.2